



SANYO Semiconductors

DATA SHEET

CPH3116 / CPH3216 — PNP / NPN Epitaxial Planar Silicon Transistors

DC / DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, flash.

Features

- Adoption of MBIT processes.
- Large current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.9mm).
- High allowable power dissipation.

() : CPH3116

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-50)80	V
Collector-to-Emitter Voltage	V _{CES}		(-50)80	V
Collector-to-Emitter Voltage	V _{CEO}		(-)50	V
Emitter-to-Base Voltage	V _{EBO}		(-)5	V
Collector Current	I _C		(-)1.0	A
Collector Current (Pulse)	I _{CP}		(-)3	A
Base Current	I _B		(-)200	mA
Collector Dissipation	P _C	Mounted on a ceramic board (600mm ² ×0.8mm)	0.9	W
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CBO}	V _{CB} =(-)40V, I _E =0			(-)0.1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(-)0.1	μA
DC Current Gain	h _{FE}	V _{CE} =(-)2V, I _C =(-)100mA	200		560	

Marking : CPH3116 : AR, CPH3216 : CR

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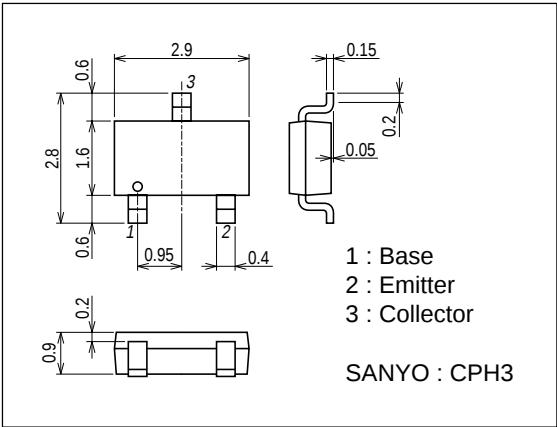
CPH3116 / CPH3216

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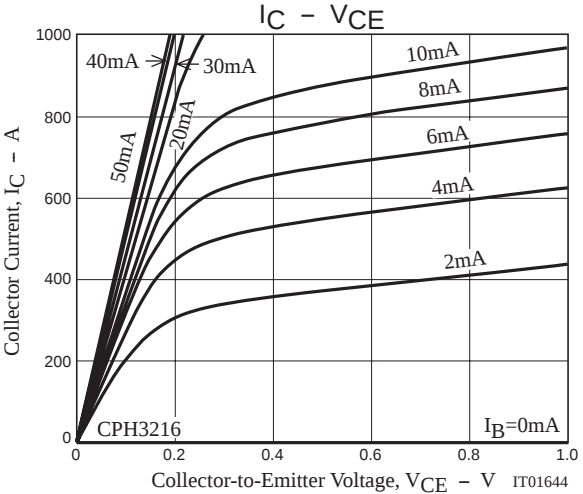
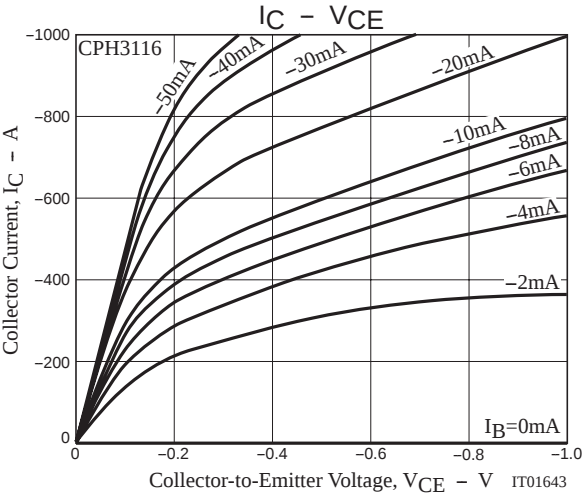
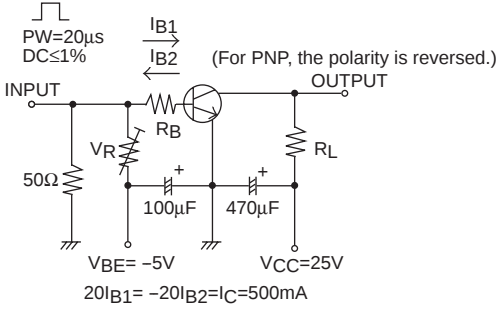
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10V, I_C=(-)300mA$		420		MHz
Output Capacitance	Cob	$V_{CB}=(-)10V, f=1MHz$		(9)6		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C=(-)500mA, I_B=(-)10mA$		(-280)	(-430)	mV
				130	190	mV
	$V_{CE(sat)2}$	$I_C=(-)300mA, I_B=(-)6mA$		(-145)	(-220)	mV
				90	135	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)500mA, I_B=(-)10mA$		(-)0.81	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-50)			V
			80			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C=(-)100\mu A, R_{BE}=0$	(-50)			V
			80			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-50)			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-5)			V
Turn-ON Time	t_{on}	See specified test circuit.		35		ns
Storage Time	t_{stg}	See specified test circuit.		(170)		ns
				330		ns
Fall Time	t_f	See specified test circuit.		(30)40		ns

Package Dimensions

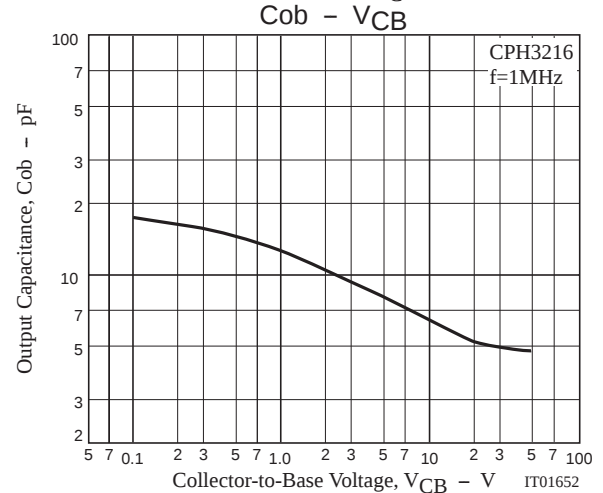
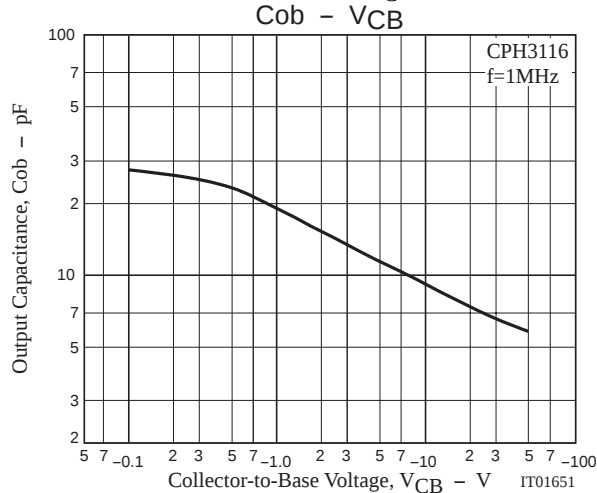
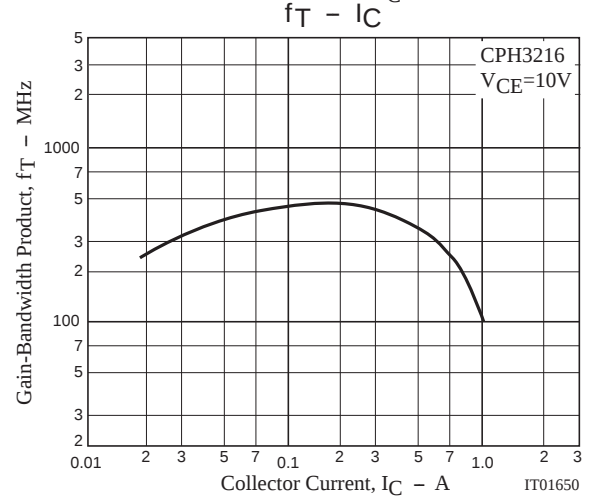
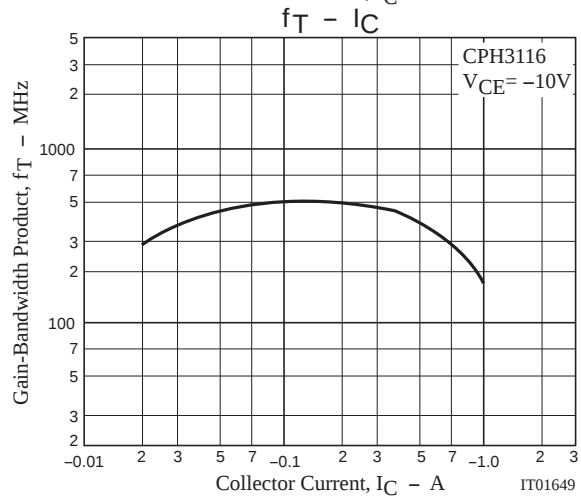
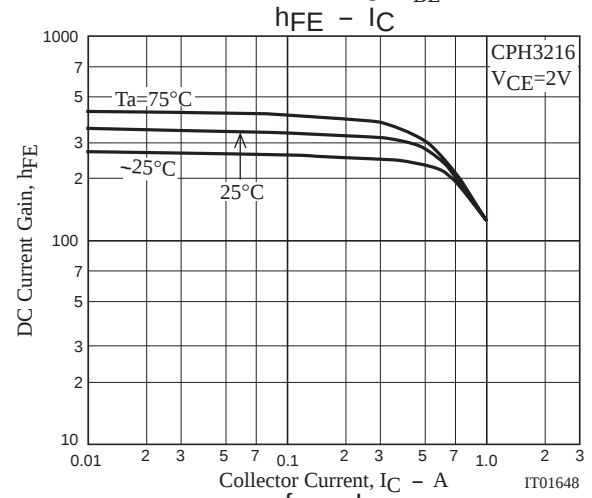
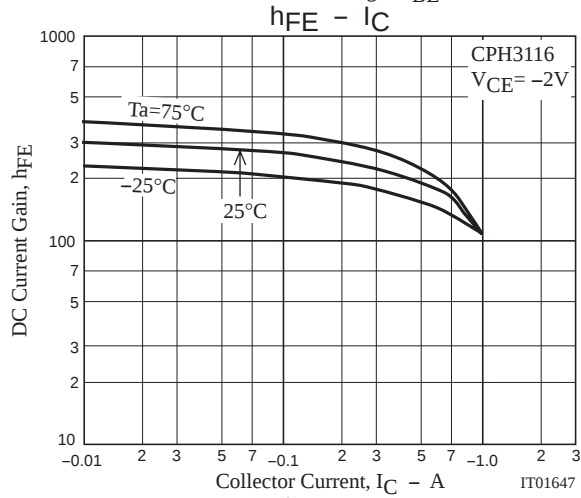
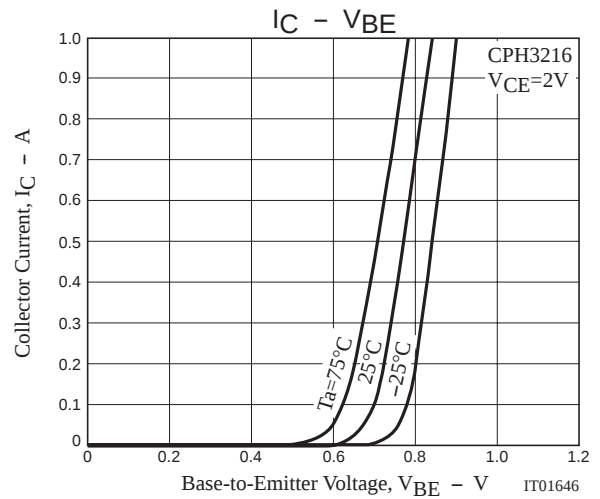
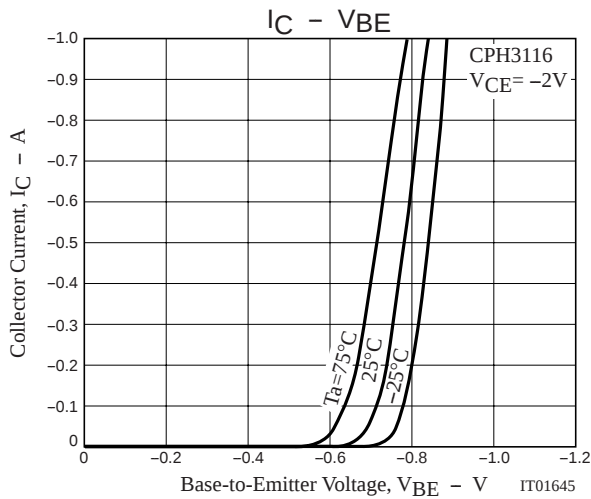
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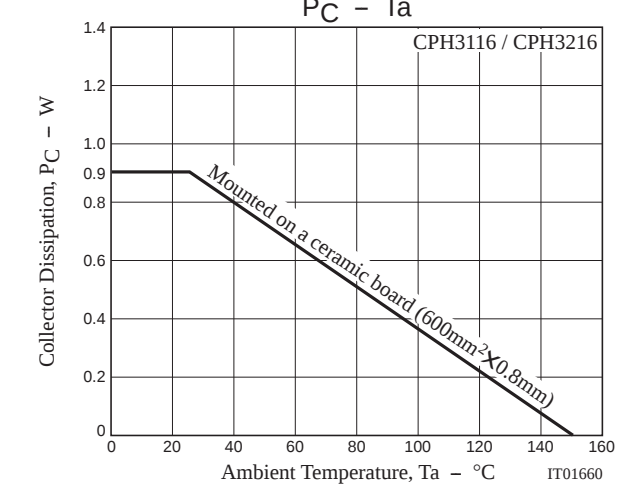
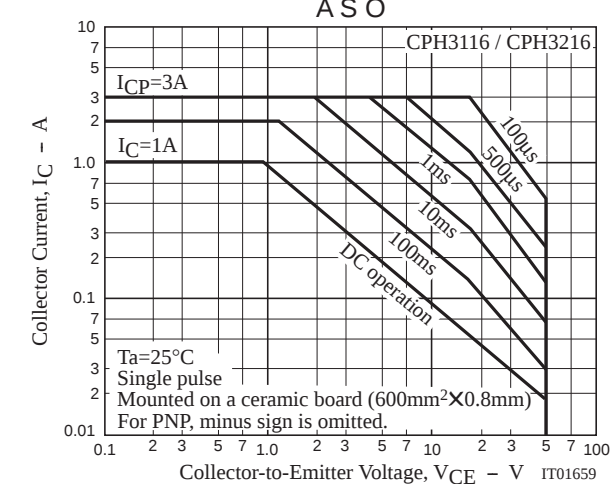
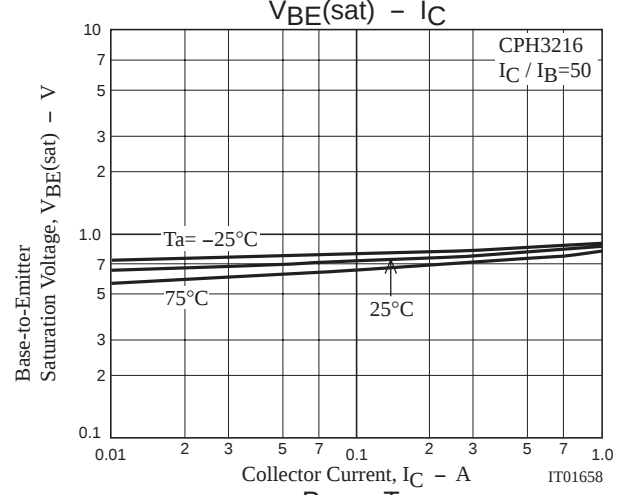
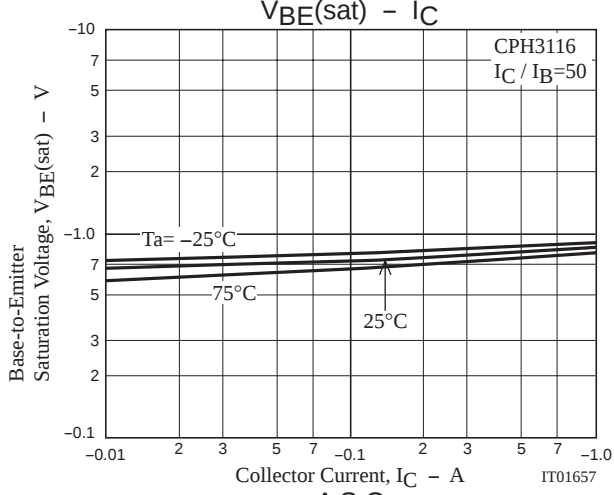
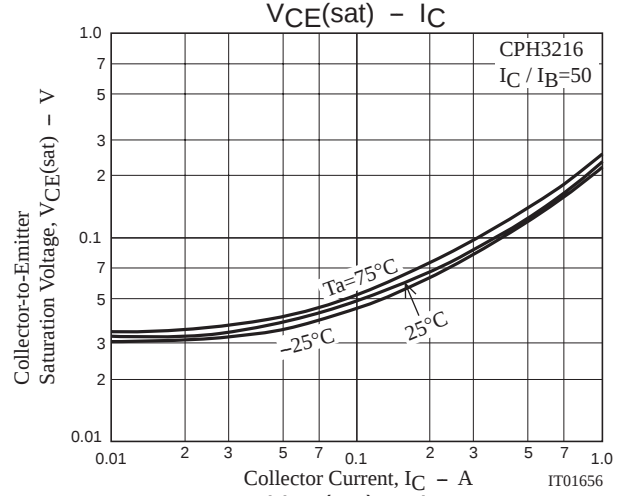
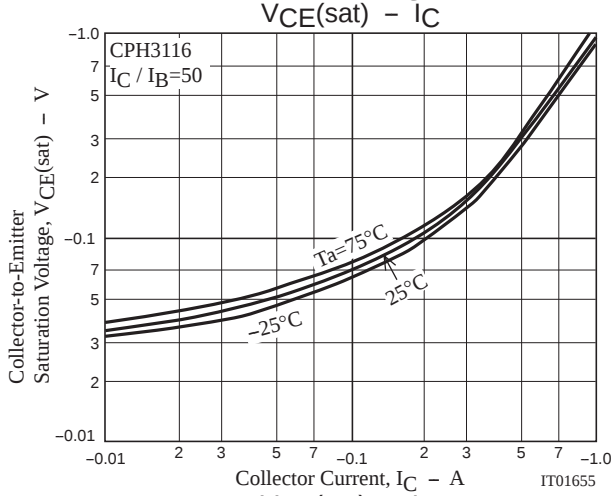
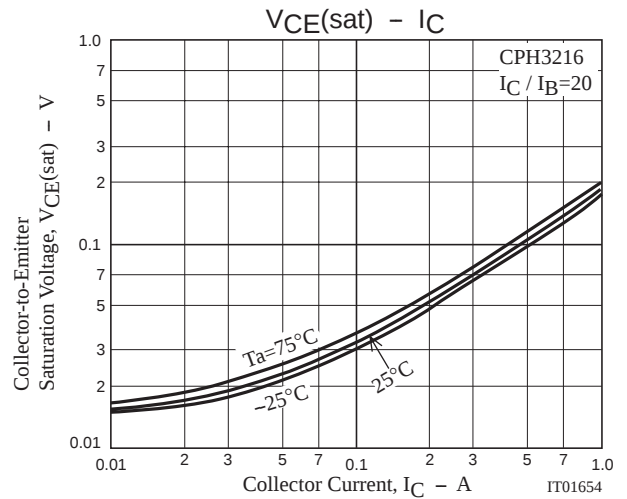
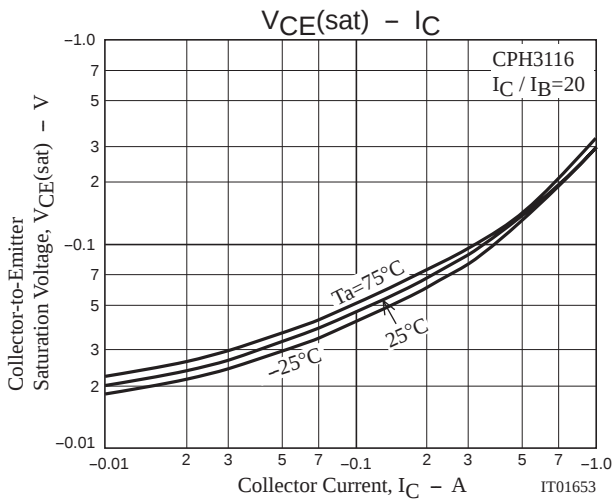


Switching Time Test Circuit



CPH3116 / CPH3216





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